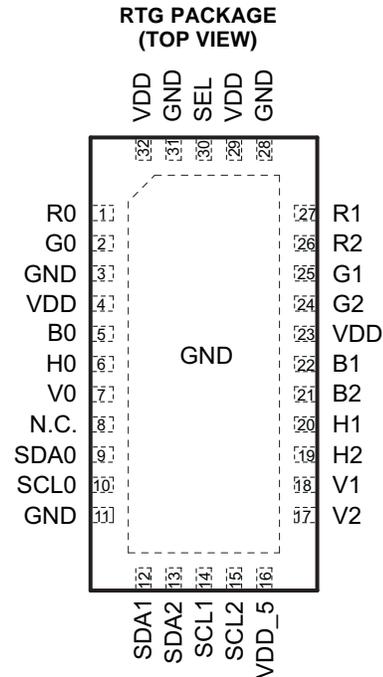


7-CHANNEL, 1:2 VIDEO SWITCH WITH INTEGRATED LEVEL SHIFTERS

 Check for Samples: [TS3V713EL](#)

FEATURES

- Supports 7-channel VGA Signals (R, G, B, H_{SYNC}, V_{SYNC}, DDC CLK, and DDC DAT)
- Operating Voltage
 - V_{DD} = 3.3 V ±10%
 - V_{DD_5} = 5 V ±10%
- High Bandwidth of 1.3 GHz (–3 dB)
- R, G, B Switches
 - R_{ON} = 4 Ω (Typ.)
 - C_{ON} = 8 pF (Typ.)
- Integrated Level Shifting Buffers for H_{SYNC} and V_{SYNC} Channels
- Voltage Clamping NMOS Switches for SCL and SDA Channels
- ESD Performance (Pins 12–15, 17–22, 24–27)
 - ±2-kV Contact Discharge (IEC61000-4-2)
 - 8 kV Human Body Model (JESD22-A114E)
- ESD Performance (All Pins)
 - 4 kV Human Body Model (JESD22-A114E)
- 32-Pin Quad Flat Pack No-Lead (QFN) Package



The exposed center pad must be connected to GND.

APPLICATIONS

- Notebook Computers
- Docking Stations
- KVM Switches

DESCRIPTION/ORDERING INFORMATION

The TS3V713EL is a high bandwidth, 7-channel video multiplexer/demultiplexer for switching between a single VGA source and one of two end points. The device is designed for ensuring video signal integrity and minimizing video signal attenuation by providing high bandwidth of 1.3 GHz.

The TS3V713EL has integrated level shifting buffers for the H_{SYNC} and V_{SYNC} signals which provide voltage level translation between 3.3V and 5V logic. The SCL and SDA lines use NMOS switches which clamp the output voltage to 1 V below V_{DD}.

The video signals are protected against ESD with integrated diodes to V_{DD} and GND that support levels up to ±2 kV Contact Discharge (IEC61000-4-2) and 8 kV Human Body Model (JESD22-A114E).

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RTG	Tape and reel	TS3V713ELRTGR	TF713EL

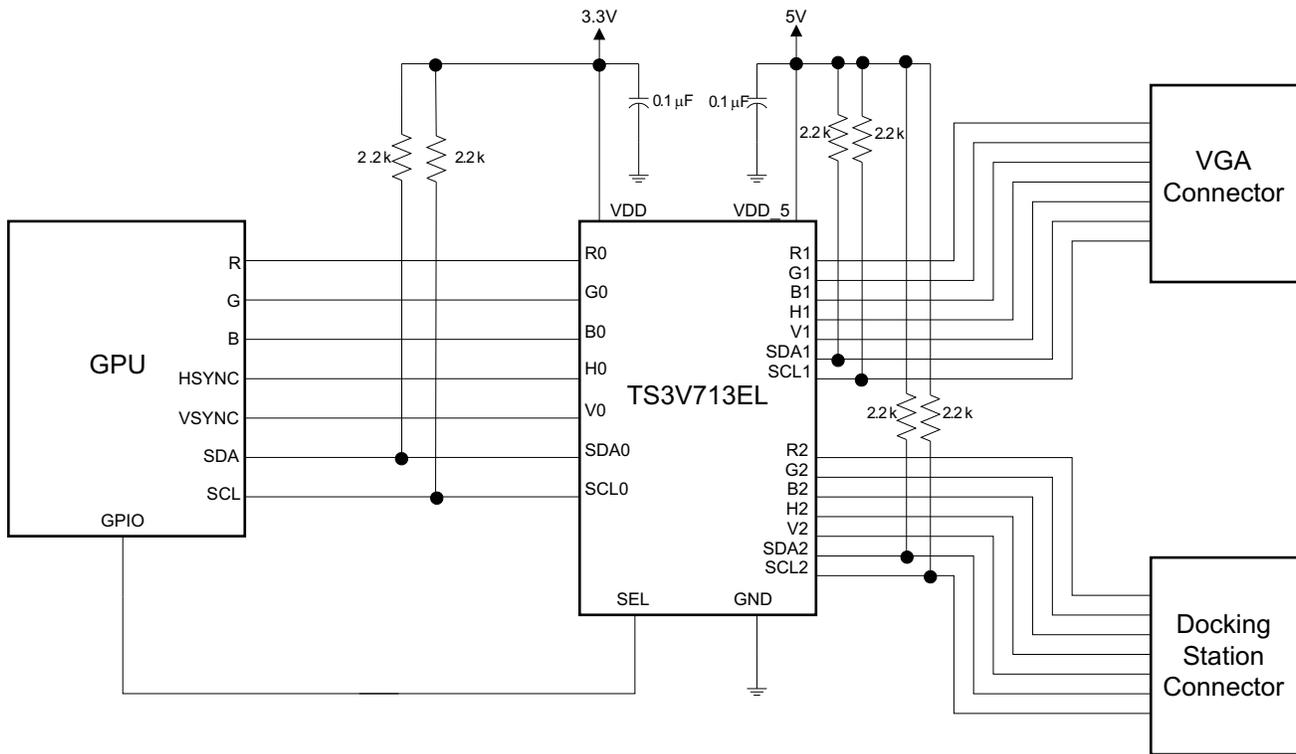
(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

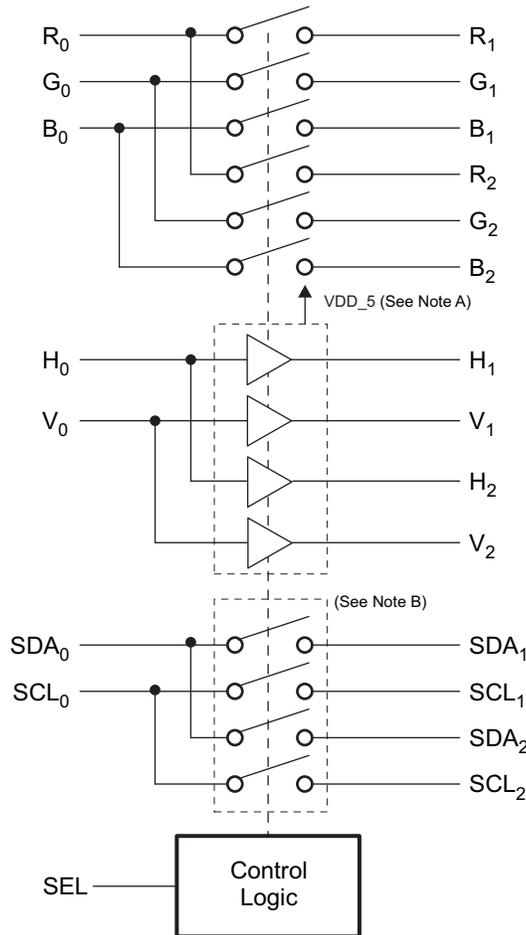


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TYPICAL APPLICATION DIAGRAM



LOGIC DIAGRAM



- A. Supply for H_{SYNC} and V_{SYNC} translators
- B. Output clamped to V_{DD} – 1 V

FUNCTION TABLE

SEL	FUNCTION	
	R ₀ , G ₀ , B ₀ , H ₀ , V ₀ , SCL ₀ , SDA ₀	Hi-Z
L	R ₁ , G ₁ , B ₁ , H ₁ , V ₁ , SCL ₁ , SDA ₁	R ₂ , G ₂ , B ₂ , H ₂ , V ₂ , SCL ₂ , SDA ₂
H	R ₂ , G ₂ , B ₂ , H ₂ , V ₂ , SCL ₂ , SDA ₂	R ₁ , G ₁ , B ₁ , H ₁ , V ₁ , SCL ₁ , SDA ₁

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{DD}	Supply voltage range		-0.5	4.6	V
V_{DD_5}			-0.5	6.5	
$V_{I/O}$	Analog voltage range ⁽²⁾⁽³⁾	R, G, B, SCL, SDA	-0.5	$V_{DD} + 0.5$	V
V_{IN}	Digital input voltage range ⁽²⁾⁽³⁾	SEL, H, V	-0.5	6.5	V
$I_{I/OK}$	Analog port diode current	$V_{I/O} < 0$ V		-50	mA
I_{IK}	Digital input clamp current	$V_{IN} < 0$ V		-50	mA
$I_{I/O}$	ON-state switch current	R, G, B, SCL, SDA	-128	128	mA
I_{DD}	Continuous current through V_{DD} or GND		-100	100	mA
I_{GND}					
θ_{JA}	Package thermal impedance ⁽⁴⁾	RTG package ⁽⁴⁾		39.2	°C/W
T_{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4) The package thermal impedance is calculated in accordance with JESD 51-1.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V_{DD}	Supply voltage		3	3.6	V
V_{DD_5}	Supply voltage for H and V channels		4.5	5.5	V
V_{IN}	Digital control input voltage	SEL, H, V	0	5.5	V
V_{IH}	High-level control input voltage	SEL, H, V	2		V
V_{IL}	Low-level control input voltage	SEL, H, V		0.8	V
I_{OH}	High-level output current	H, V		-8	mA
I_{OL}	Low-level output current	H, V		8	mA
T_A	Operating free-air temperature		-40	85	°C

- (1) All unused control inputs of the device must be held at V_{DD} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

ELECTRICAL CHARACTERISTICS⁽¹⁾

 over recommended operating free-air temperature range, $V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$, $V_{DD_5} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS			MIN	TYP ⁽²⁾	MAX	UNIT
V_{IK}	Digital input clamp voltage	SEL, H, V	$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$I_{IN} = -18\text{ mA}$			-0.8	-1.2	V
r_{ON}	ON-state resistance	R, G, B	$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$0\text{ V} \leq V_{I/O} \leq V_{DD}$,	$I_{I/O} = -40\text{ mA}$		3	6	Ω
		SCL, SDA				4	8		
$r_{ON(\text{flat})}$	ON-state resistance flatness ⁽³⁾	R, G, B	$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$V_{I/O} = 1.5\text{ V}$ and V_{DD} ,	$I_{I/O} = -40\text{ mA}$		0.2	1	Ω
Δr_{ON}	ON-state resistance match between channels ⁽⁴⁾	R, G, B	$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$0\text{ V} \leq V_{I/O} \leq V_{DD}$,		$I_{I/O} = -40\text{ mA}$		0.2	1
I_{IH}	Digital input high leakage current	SEL, H, V	$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$V_{IN} = V_{DD}$					± 1
I_{IL}	Digital input low leakage current	SEL, H, V	$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$V_{IN} = \text{GND}$				± 1	μA
I_{OFF}	Leakage under power off conditions	All outputs	$V_{DD} = 0\text{ V}$, $V_{DD_5} = 0\text{ V}$,	$V_{I/O} = 0$ to 3.6 V, $V_{IN} = 0$ to 5.5 V				± 1	μA
C_{IN}	Digital input capacitance	SEL, H, V	$f = 10\text{ MHz}$	$V_{IN} = 0$,			4		pF
C_{OFF}	Switch OFF capacitance	R, G, B	$f = 10\text{ MHz}$	$V_{I/O} = 0\text{ V}$,	Output open, Switch OFF		2.5		pF
		SCL, SDA				2.3			
C_{ON}	Switch ON capacitance	R, G, B	$f = 10\text{ MHz}$	$V_{I/O} = 0\text{ V}$,	Output open, Switch ON		8		pF
		SCL, SDA				8.2			
V_{OH}	High-level output voltage	H, V	$V_{IN} = V_{IH}$,	$I_{OH} = -8\text{ mA}$		3.8			V
V_{OL}	Low-level output voltage	H, V	$V_{IN} = V_{IH}$,	$I_{OL} = 8\text{ mA}$				0.5	V
$V_{HYS T}$	Voltage hysteresis	H, V					200	300	mV
I_{DD}	V_{DD} supply current		$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$V_{IN} = V_{DD}$ or GND,	$I_{I/O} = 0\text{ mA}$,		200	500	μA
I_{DD_5}	V_{DD_5} supply current		$V_{DD} = 3.6\text{ V}$, $V_{DD_5} = 5.5\text{ V}$,	$V_{IN} = V_{DD}$ or GND,		$I_{I/O} = 0\text{ mA}$,			50

- (1) V_I , V_O , I_I , and I_O refer to I/O pins. V_{IN} refers to the control inputs.
- (2) All typical values are at $V_{DD} = 3.3\text{ V}$, $V_{DD_5} = 5\text{ V}$ (unless otherwise noted), $T_A = 25^\circ\text{C}$.
- (3) $r_{ON(\text{flat})}$ is the difference of r_{ON} in a given channel at specified voltages.
- (4) Δr_{ON} is the difference of r_{ON} from center port to any other ports.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$, $V_{DD_5} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP	MAX	UNIT
$t_{pd}^{(1)}$	R_0, G_0, B_0	R_1, G_1, B_1 or R_2, G_2, B_2		0.25		ns
	SCL_0, SDA_0	SCL_1, SDA_1 or SCL_2, SDA_2		0.25		
	H_0, V_0	H_1, V_1 or H_2, V_2		3	7	
$t_{PHZ}, t_{PLZ}^{(2)}$	SEL	$R_1, G_1, B_1, SCL_1, SDA_1$ or $R_2, G_2, B_2, SCL_2, SDA_2$		0.5	11	ns
	SEL	H_1, V_1 or H_2, V_2		0.5	13	
$t_{PZH}, t_{PZL}^{(3)}$	SEL	$R_1, G_1, B_1, SCL_1, SDA_1$ or $R_2, G_2, B_2, SCL_2, SDA_2$		0.5	11	ns
	SEL	H_1, V_1 or H_2, V_2		0.5	13	
$t_{sk(o)}^{(4)}$		R, G, B		0.05	0.1	ns
$t_{sk(p)}^{(5)}$		R, G, B		0.05	0.1	ns

- (1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).
- (2) Line disable time: SEL to input and output; also called "SEL to Switch Turn Off Time."
- (3) Line enable time: SEL to input and output; also called "SEL to Switch Turn On Time."
- (4) Output skew between center channel to any other channel.
- (5) Skew between opposite transitions of the same output. $|t_{PHL} - t_{PLH}|$

DYNAMIC CHARACTERISTICS

over recommended operating free-air temperature range, $V_{DD} = 3.3\text{ V} \pm 0.3\text{ V}$, $V_{DD_5} = 5\text{ V} \pm 0.5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS		TYP ⁽¹⁾	UNIT
X_{TALK}	R, G, B	$R_L = 50\ \Omega$ $f = 250\text{ MHz}$	-50	dB
O_{IRR}	R, G, B	$R_L = 50\ \Omega$ $f = 250\text{ MHz}$	-40	dB
BW	R, G, B	$R_L = 50\ \Omega$ Switch ON	1.3	GHz

- (1) All typical values are at $V_{DD} = 3.3\text{ V}$, $V_{DD_5} = 5\text{ V}$ (unless otherwise noted)

TYPICAL CHARACTERISTICS

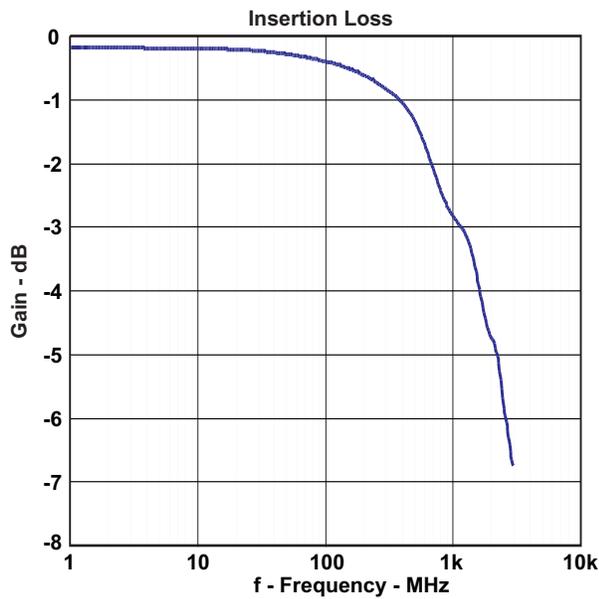


Figure 1. Gain vs Frequency

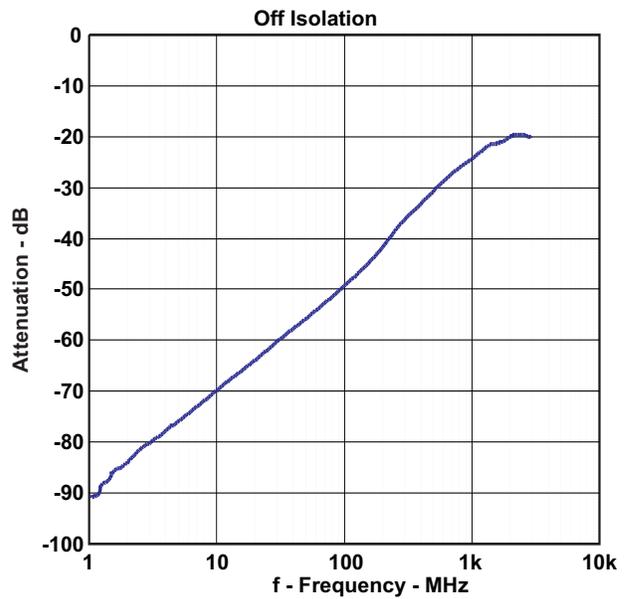


Figure 2. Off Isolation vs Frequency

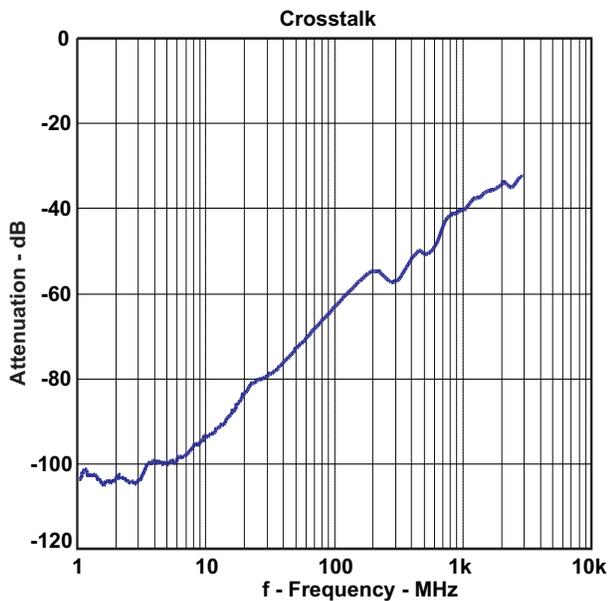


Figure 3. Crosstalk vs Frequency

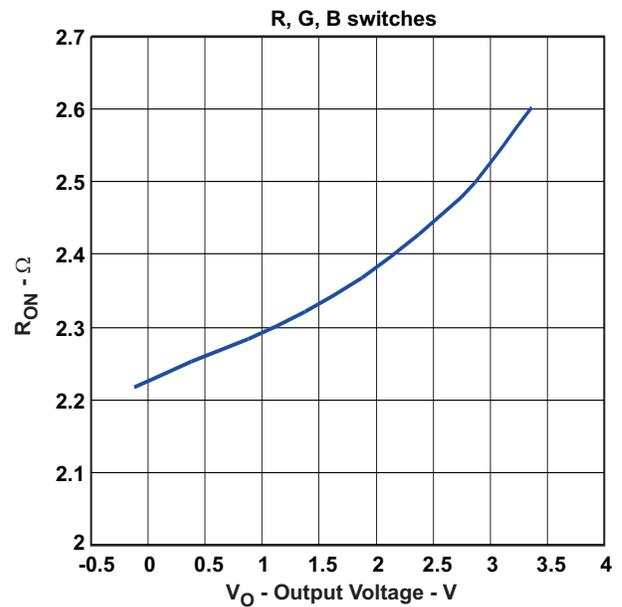


Figure 4. R_{ON} vs V_O

TYPICAL CHARACTERISTICS (continued)



Figure 5. RON vs VI

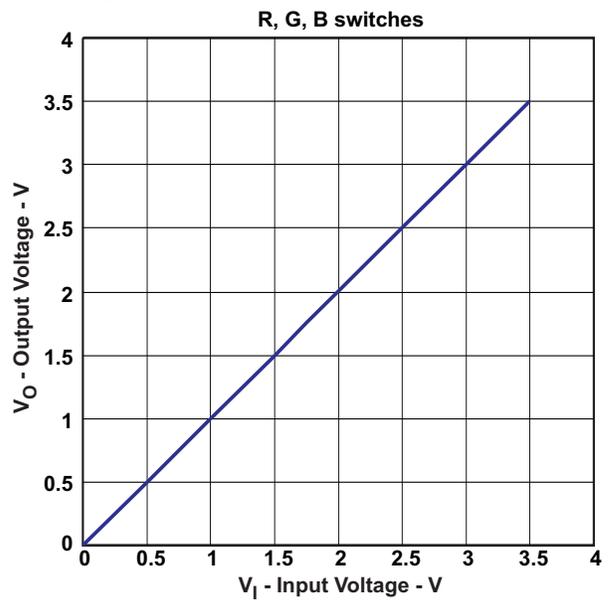


Figure 6. VO vs VI

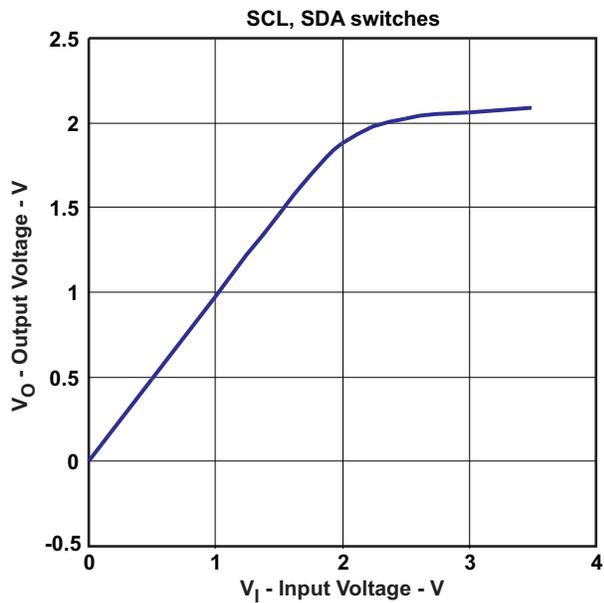


Figure 7. VO vs VI

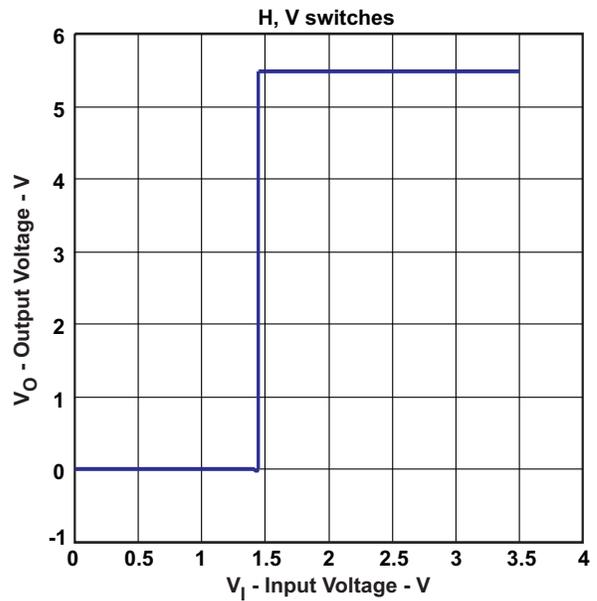
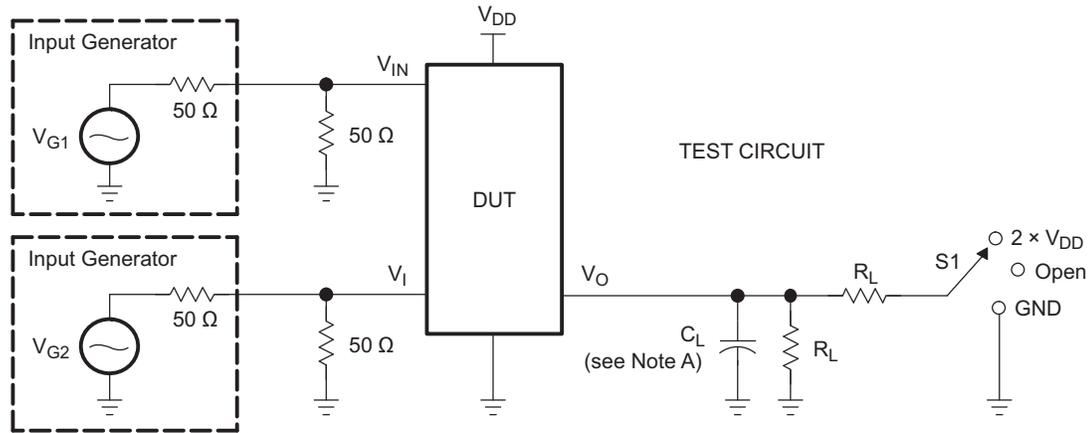


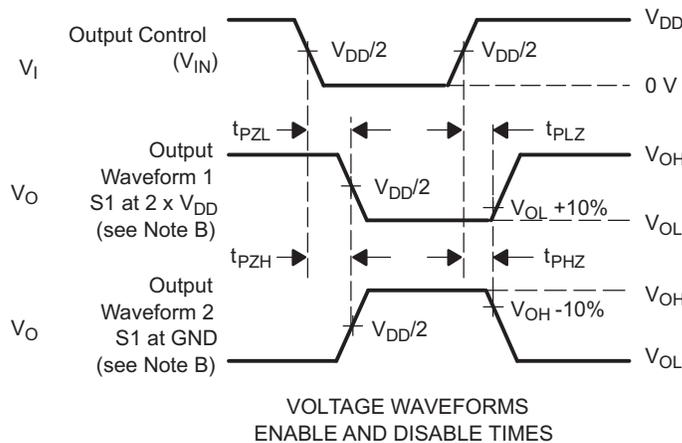
Figure 8. VO vs VI

**PARAMETER MEASUREMENT INFORMATION
(Enable and Disable Times)**



TEST	V _{DD_5}	V _{DD}	S1	R _L	V _{in}	C _L	V _Δ
t _{PLZ} /t _{PZL}	5 V ± 0.5 V	3.3 V ± 0.3 V	2 × V _{DD}	200 Ω or 1 kΩ*	GND	10 pF	0.3 V
t _{PHZ} /t _{PZH}	5 V ± 0.5 V	3.3 V ± 0.3 V	GND		V _{DD}	10 pF	0.3 V

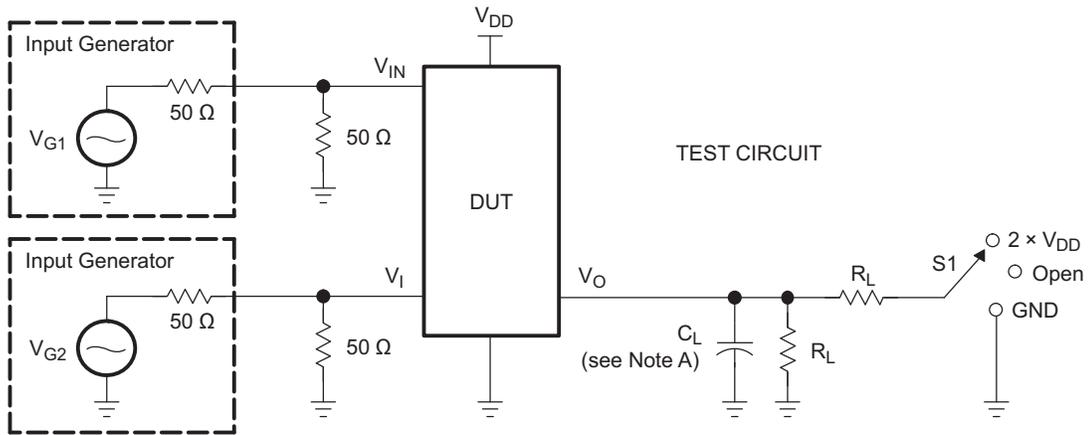
*R_L = 200 Ω applies to all switch outputs
R_L = 1 kΩ applies to all buffer outputs



- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PR ≈ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
 D. The outputs are measured one at a time, with one transition per measurement.
 E. t_{PLZ} and t_{PHZ} are the same as t_{jis}.
 F. t_{PZL} and t_{PZH} are the same as t_{en}.

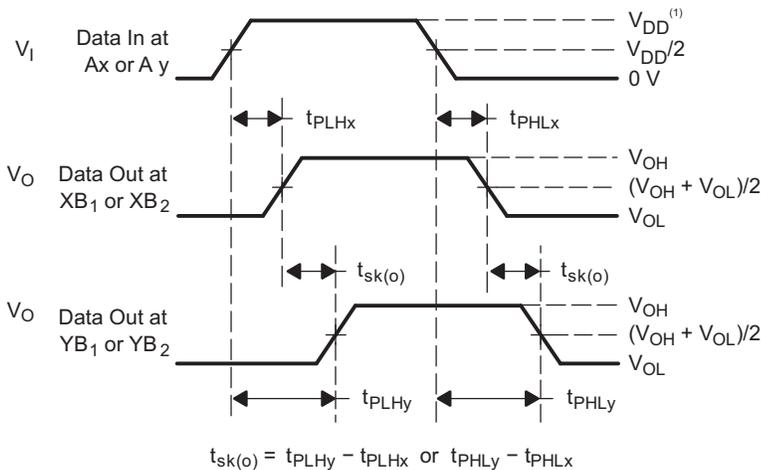
Figure 9. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION (Propagation Delay and Skew)

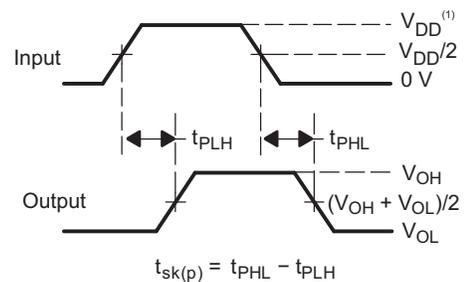


TEST	V _{DD}	V _{DD_5}	S1	R _L	V _{in}	C _L
t _{sk(o)}	3.3 V ± 0.3 V	5 V ± 0.5 V	Open	200 Ω* or 1 kΩ	V _{DD} or GND	10 pF
t _{sk(p)}	3.3 V ± 0.3 V	5 V ± 0.5 V	Open		V _{DD} or GND	10 pF

*R_L = 200 Ω applies to all switch outputs
R_L = 1 kΩ applies to all buffer outputs



VOLTAGE WAVEFORMS
OUTPUT SKEW [t_{sk(o)}]

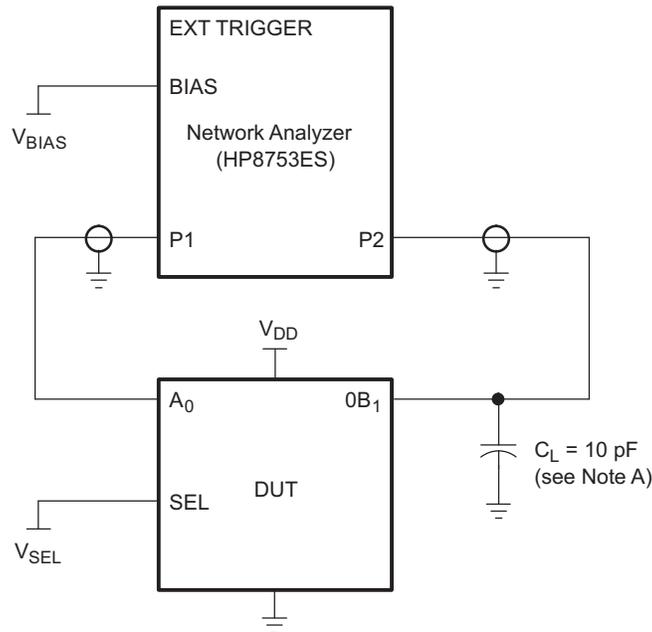


VOLTAGE WAVEFORMS
PULSE SKEW [t_{sk(p)}]

- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
 D. The outputs are measured one at a time, with one transition per measurement.
 (1) 2 V ± 0.2 V for SCL, SDA

Figure 10. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



A. C_L includes probe and jig capacitance.

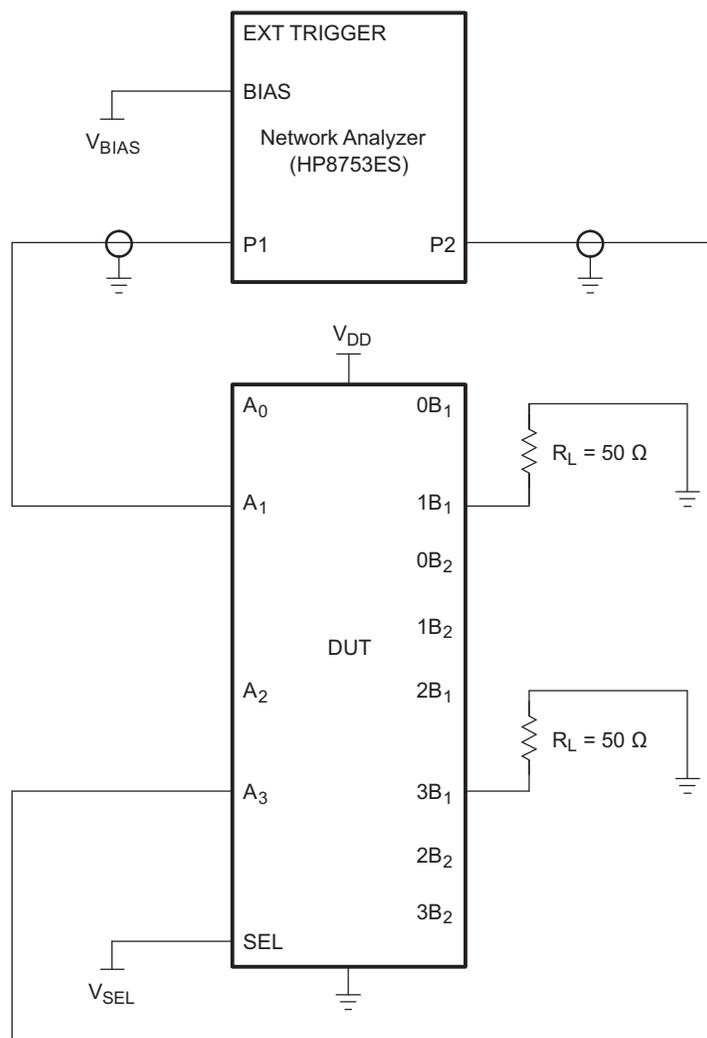
Figure 11. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when $V_{SEL} = 0$ and A_0 is the input, the output is measured at $0B_1$. All unused analog I/O ports are left open.

HP8753ES Setup

Average = 4
 RBW = 3 kHz
 $V_{BIAS} = 0.35 \text{ V}$
 ST = 2 s
 P1 = 0 dBm

PARAMETER MEASUREMENT INFORMATION (continued)



- A. C_L includes probe and jig capacitance.
- B. A 50- Ω termination resistor is needed to match the loading of the network analyzer.

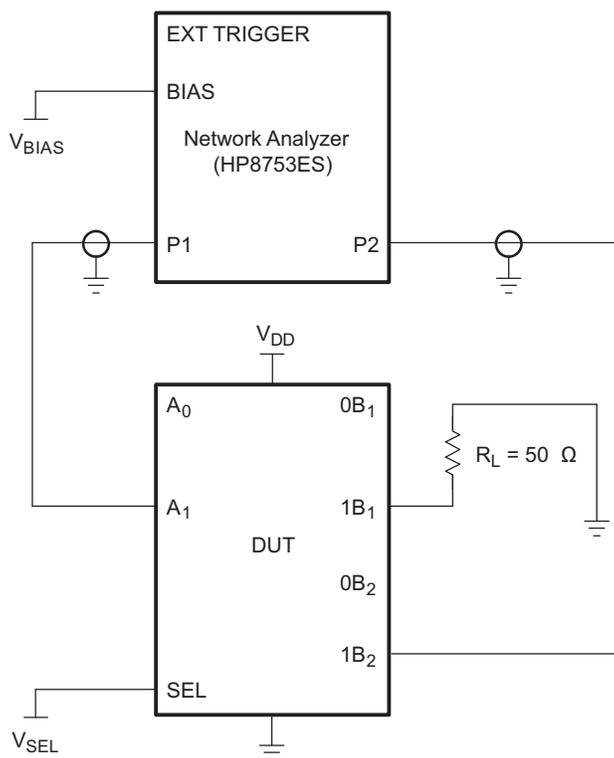
Figure 12. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_{SEL} = 0$ and A_1 is the input, the output is measured at A_3 . All unused analog input (A) ports are connected to GND, and the output (B) ports are left open.

HP8753ES Setup

Average = 4
 RBW = 3 kHz
 $V_{BIAS} = 0.35$ V
 ST = 2 s
 P1 = 0 dBm

PARAMETER MEASUREMENT INFORMATION (continued)



- A. C_L includes probe and jig capacitance.
- B. A 50- Ω termination resistor is needed to match the loading of the network analyzer.

Figure 13. Test Circuit for Off Isolation (O_{IRR})

Off isolation is measured at the output of the OFF channel. For example, when $V_{SEL} = GND$ and A_s is the input, the output is measured at $1B_2$. All unused analog input (A) ports are connected to GND, and the output (B) ports are left open.

HP8753ES Setup

- Average = 4
- RBW = 3 kHz
- $V_{BIAS} = 0.35 V$
- ST = 2 s
- P1 = 0 dBm

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS3V713ELRTGR	ACTIVE	WQFN	RTG	32	3000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	TF713EL	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

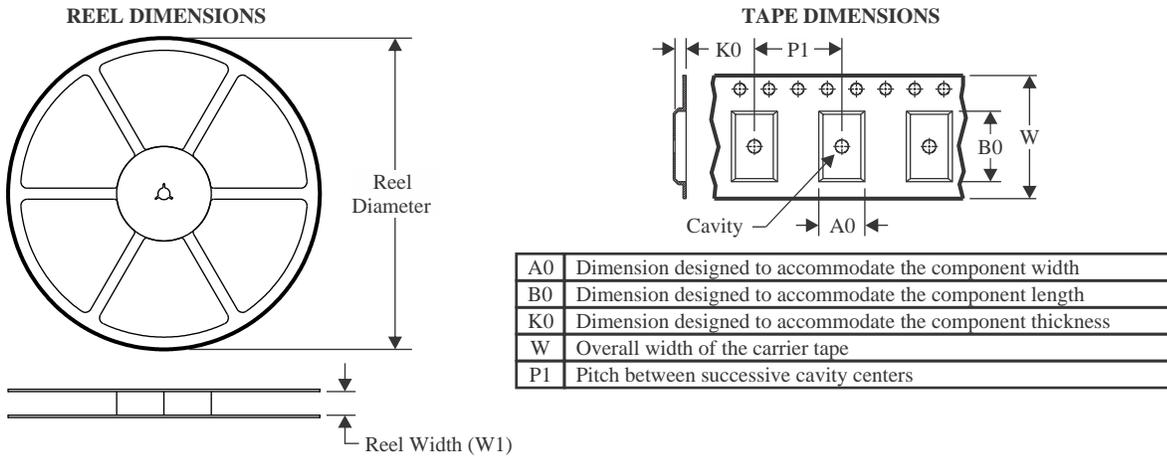
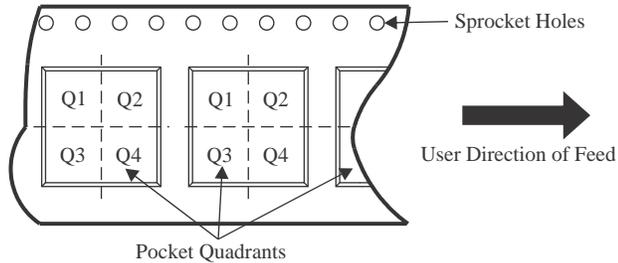
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

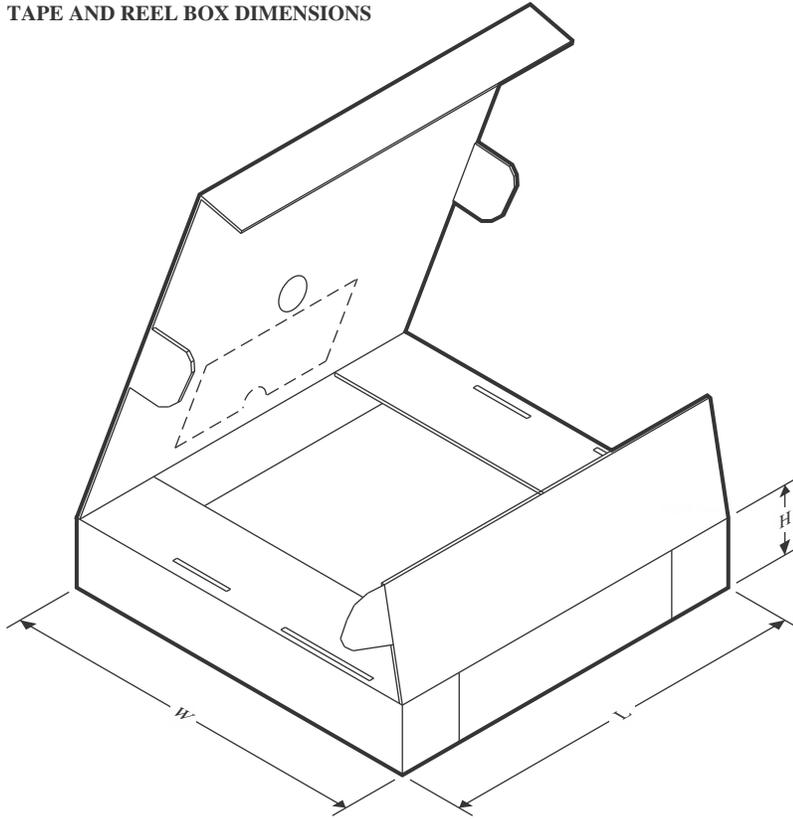
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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3V713ELRTGR	WQFN	RTG	32	3000	330.0	16.4	3.3	6.3	1.0	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS


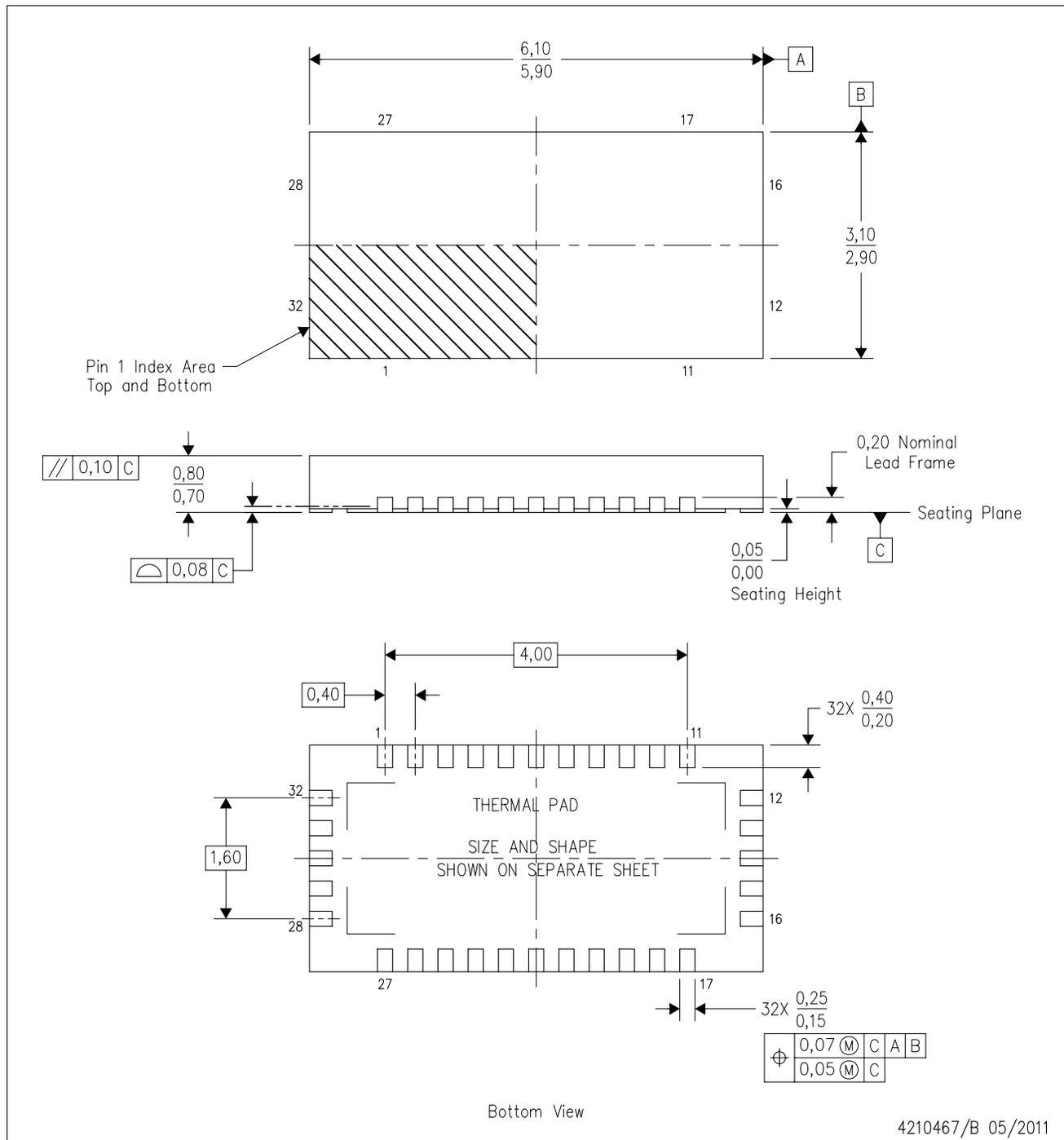
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3V713ELRTGR	WQFN	RTG	32	3000	356.0	356.0	35.0

MECHANICAL DATA

RTG (R-PWQFN-N32)

PLASTIC QUAD FLATPACK NO-LEAD



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Reference JEDEC MO-220.

THERMAL PAD MECHANICAL DATA

RTG (R-PWQFN-N32)

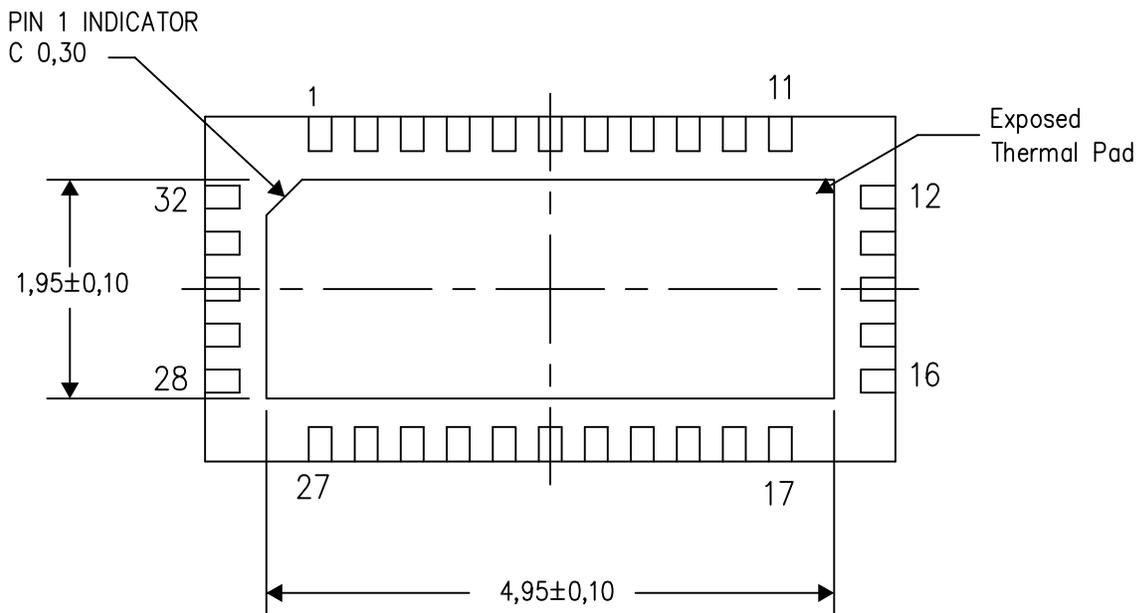
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4210534-2/D 12/13

NOTE: All linear dimensions are in millimeters

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